

Features

- Plastic package has Underwriters Laboratory Flammability Classification 94V-0
- For surface mounted applications
- High current capability
- Very low forward voltage drop
- Epitaxial construction
- Metal-Semiconductor junction with guardring
- For use in low voltage, high frequency inverters, Free-wheeling, and polarity protection applications

EC76SK22~EC76SK26



DO-214AA(SMB)

Applications

- Case : JEDEC DO-214AA(SMB) molded plastic
- Polarity : Indicated by cathode band
- Weight : 0.003 ounce, 0.093 gram

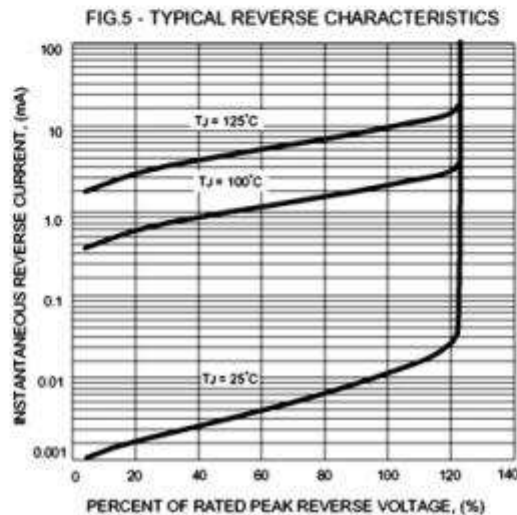
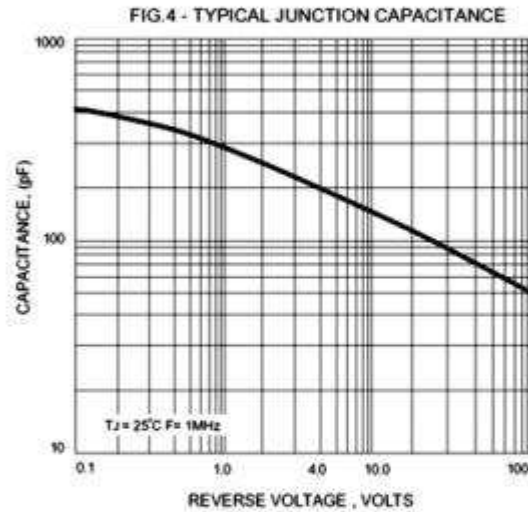
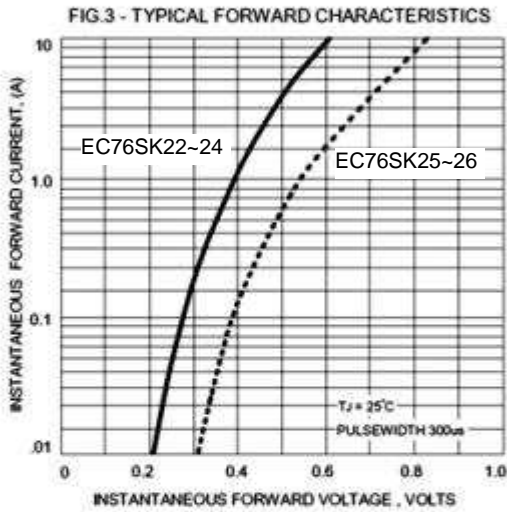
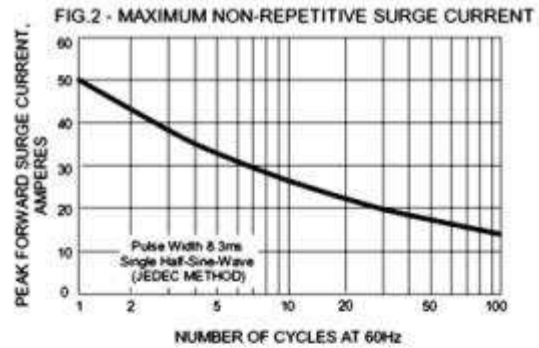
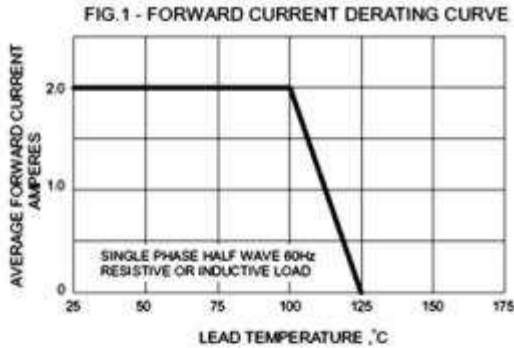
Maximum Ratings and Electrical Characteristics

Ratings at 25°C ambient temperature unless otherwise specified. Single phase, half wave, 60Hz, resistive or inductive load. For capacitive load, derate current by 20%

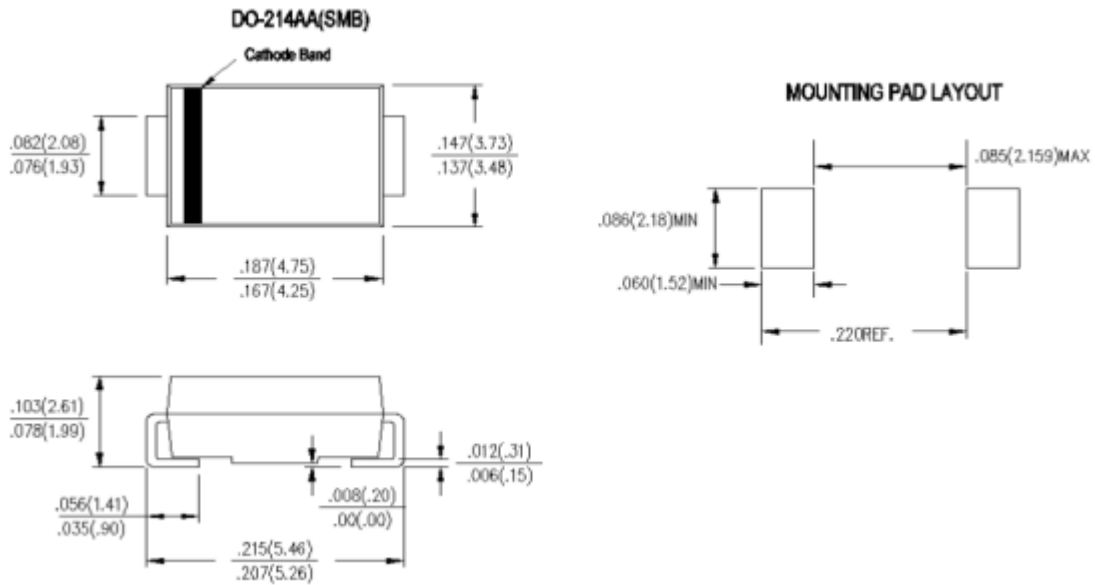
Parameter	Symbol	EC76SK22	EC76SK24	EC76SK26	Unit
Maximum repetitive peak reverse voltage	VRRM	20	40	60	V
Maximum RMS voltage	VRMS	14	28	42	V
Maximum DC blocking voltage	VDC	20	40	60	V
Maximum average forward rectified current @TL=100°C	IF(AV)	2.0			A
Peak forward surge current, 8.3ms single half sine-wave superimposed on rated load (JEDEC Method)	IFSM	50.0			A
Maxmum forward voltage at 3.0ADC @TJ =25°C @TJ =100°C	VF	0.50		0.70	V
Maximum DC reverse current at rated DC blocking voltage @TJ =25°C @TJ =100°C	IR		0.5 20		mA
Typical junction capacitance (Note 1)	CJ	200			pF
Typical thermal resistance (Note 2,3)	RθJL RθJA		25 85		°C/W
Operating junction temperature range	TJ	-55 to +125			°C
Storage temperature range	TSTG	-55 to +150			°C

- Notes: 1. Measured at 1.0MHz and applied reverse voltage of 4.0V DC.
 2. Thermal Resistance Junction to Lead.
 3. Thermal Resistance Junction to Ambient.

Typical Performance Curves



Product Dimension



Device	Package	Net Weight	Carrier	Quantity	HSF Status
EC76SK2x	DO-214AA(SMB)	0.093g	Tape & Reel	3000pcs/reel	RoHS compliant